

4A, 50V - 1000V Standard Bridge Rectifier

FEATURES

- AEC-Q101 qualified available
- Glass passivated chip junction
- Ideal for printed circuit board
- High case dielectric strength
- Typical IR less than 0.1 μ A
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

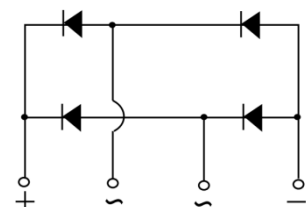
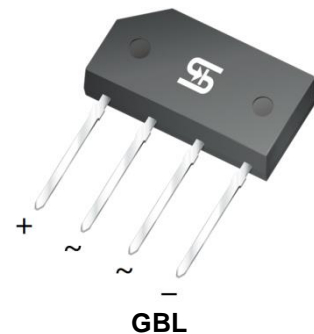
APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application

MECHANICAL DATA

- Case: GBL
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 2.00g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	4	A
V_{RRM}	50 - 1000	V
I_{FSM}	120	A
$T_{J\ MAX}$	150	$^{\circ}$ C
Package	GBL	
Configuration	Quad	



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C unless otherwise noted)

PARAMETER	SYMBOL	GBLA 005	GBLA 01	GBLA 02	GBLA 04	GBLA 06	GBLA 08	GBLA 10	UNIT
Marking code on the device		GBLA 005	GBLA 01	GBLA 02	GBLA 04	GBLA 06	GBLA 08	GBLA 10	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Forward current	$T_C = 50^{\circ}$ C	4							A
	$T_A = 40^{\circ}$ C	3							A
Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	120							A
Rating for fusing ($t < 8.3ms$)	I^2t	59							A ² s
Junction temperature	T_J	- 55 to +150							$^{\circ}$ C
Storage temperature	T_{STG}	- 55 to +150							$^{\circ}$ C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance	$R_{\theta JL}$	10	°C/W
Junction-to-ambient thermal resistance	$R_{\theta JA}$	47	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 4\text{A}, T_J = 25^\circ\text{C}$	V_F	-	1	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	5	μA
	$T_J = 125^\circ\text{C}$		-	500	μA
Junction capacitance per diode	1MHz, $V_R = 4.0\text{V}$	C_J	95	-	pF
			40	-	pF

Notes:

1. Pulse test with $PW = 0.3\text{ms}$
2. Pulse test with $PW = 30\text{ms}$

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
GBLx	GBL	25 / Tube
GBLxH	GBL	25 / Tube

Notes:

1. "x" defines voltage from 50V(GBLA005) to 1000V(GBLA10)
2. "H" means AEC-Q101 qualified

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

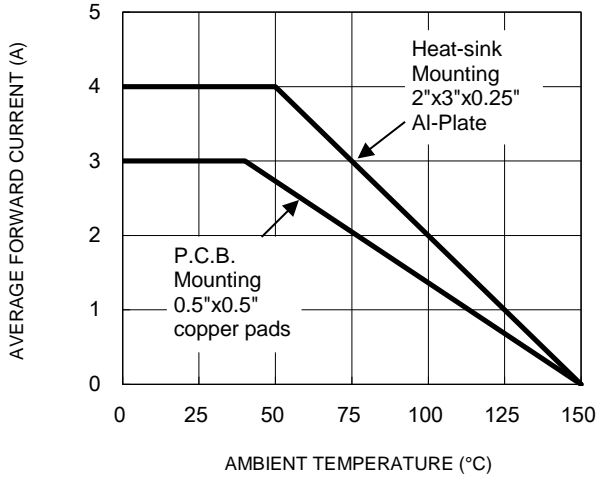


Fig.2 Typical Junction Capacitance

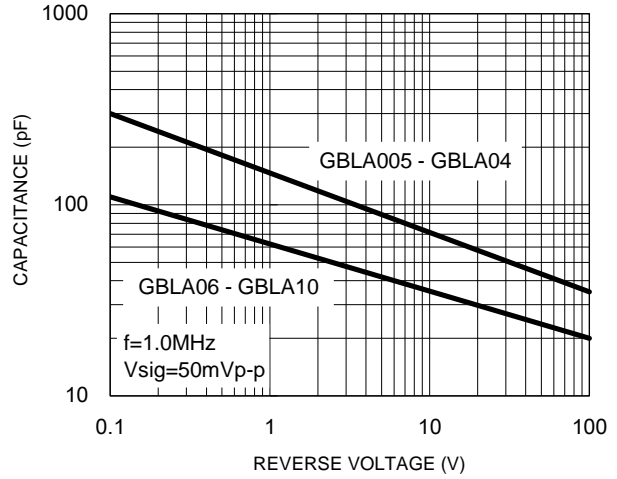


Fig.3 Typical Reverse Characteristics

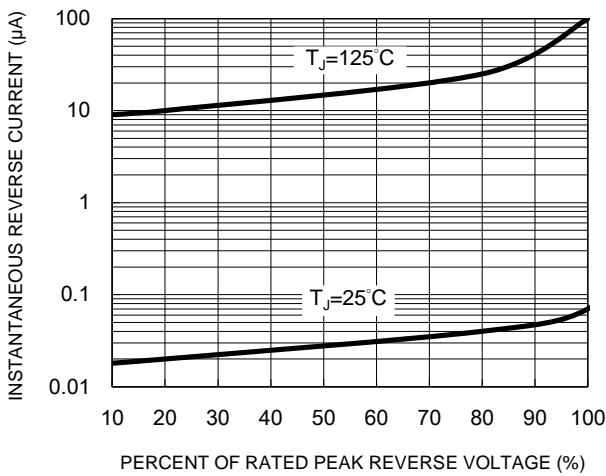


Fig.4 Typical Forward Characteristics

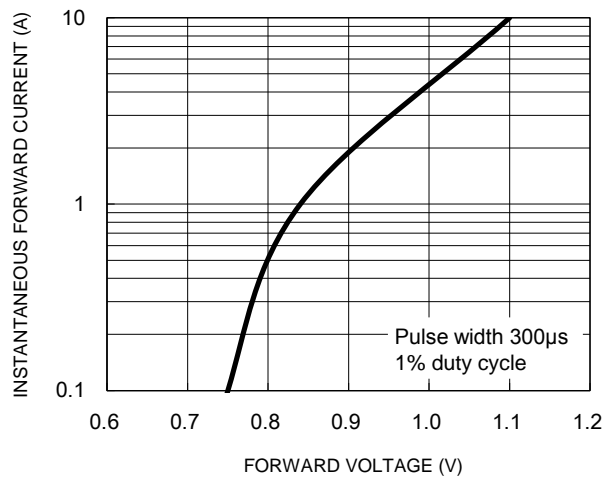
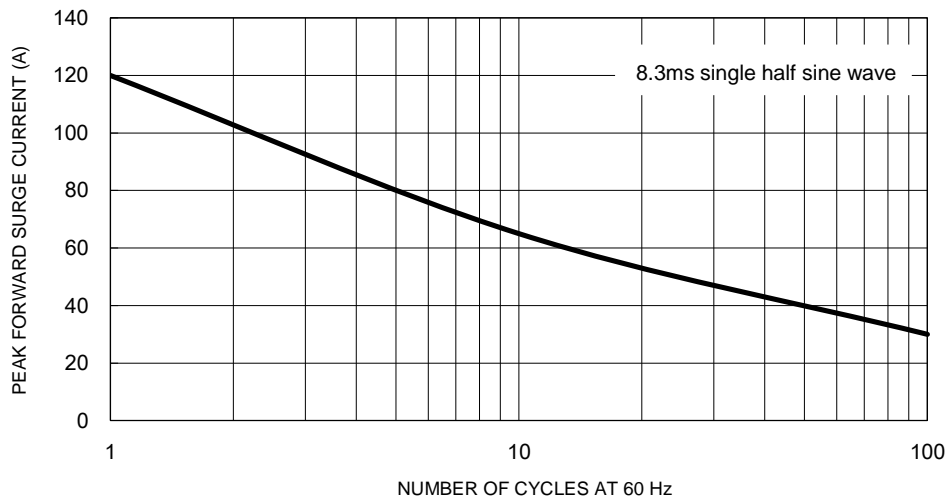
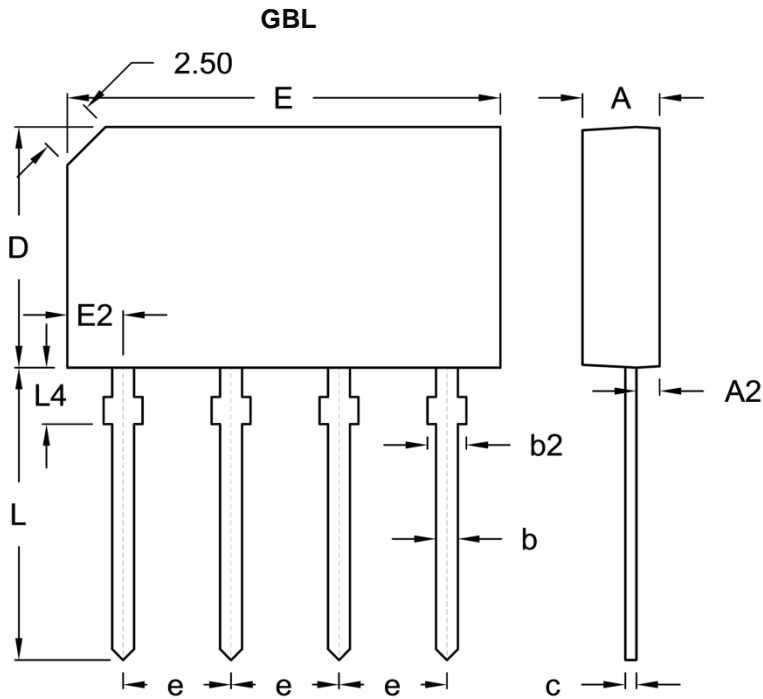


Fig.5 Maximum Non-Repetitive Forward Surge Current



PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	3.30	3.70	0.130	0.146
A2	0.80	1.20	0.031	0.047
b	0.90	1.10	0.035	0.043
b2	1.30	2.00	0.051	0.079
c	0.40	0.60	0.016	0.024
D	10.70	11.30	0.421	0.445
E	19.70	20.30	0.776	0.799
E2	2.30	2.70	0.091	0.106
e	4.80	5.20	0.189	0.205
L	13.00	14.00	0.512	0.551
L4	2.30	2.70	0.091	0.106

MARKING DIAGRAM



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code